NSN 5961-01-419-7854

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View Online at https://aerobasegroup.com/nsn/5961-01-419-7854
Inclosure Material:
Ceramic and metal
Overall Length:
Between 0.665 inches and 0.685 inches
Terminal Length:
0.510 inches
Overall Height:
Between 0.249 inches and 0.260 inches
Overall Width:
Between 0.535 inches and 0.545 inches
Function For Which Designed:
Switching
Mounting Facility Quantity:
1
Internal Configuration:
Field effect
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-254aa
Mounting Method:
Unthreaded hole
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
100.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source and 20.0 gate to source voltage
Current Rating Per Characteristic:
112.00 amperes off-state current, peak
Power Rating Per Characteristic:
125.0 watts total power dissipation
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius ambient air
Test Data Document:
81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
3 uninsulated wire lead
Specification Data:
81349-mil-prf-19500/596 government specification
Shelf Life:
N/a
Unit Of Measure:

Yes - demil/mli

Demilitarization:

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Mil-std (military Standard):

Mil-prf-19500 spec.